

## TYN616

单向可控硅  
THYRISTOR版本号  
201603-A

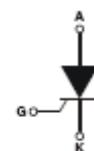
## 产品概述 GENERAL DESCRIPTION

**TYN616** 单向可控硅采用穿通隔离台面结构，复合玻璃钝化PN结表面保护工艺技术， $dv/dt$ 高，可靠性高，适用于控温、调光、马达控制。

**TYN616** Thyristor is fabricated using separation diffusion processes ,the junction termination areas are passivated with glass. Thanks to highly  $dv/dt$  and reliability,the Triacs series is suitable for domestic lighting ,heating and motor speed controllers.

## 主要参数 MAIN CHARACTERISTICS

参数 Parameter	数值 Value	单位 Unit
$I_T(RMS)$	16	A
$V_{DRM}/V_{RRM}$	600	V
$I_{GT}$	15	mA



TO-252

## 产品特性 FEATURES

- $dv/dt$ 高
- 通态压降低
- Rohs环保产品
- Highly  $dv/dt$
- Low on-state voltage
- Rohs Products

## 应用领域 APPLICATIONS

主要应用于调光、控温、马达控制。

domestic lighting ,heating and motor speed controllers.

**极限值(除非另有规定, Tj=25°C) ABSOLUTE RATINGS**

(Tj=25°C,unless otherwise specified)

符号 Symbol	参数 Parameter			数值 Value	单位 Unit
I <sub>T(RMS)</sub>	RMS 通态电流 RMS on-state current (full sine wave)	T <sub>C</sub> =90°C		16	A
I <sub>TSM</sub>	通态峰值浪涌电流 Non repetitive surge peak on-state current	F=50Hz, t=20ms		160	A
I <sup>2</sup> t	I <sup>2</sup> t 耗散值 I <sup>2</sup> t value for fusing	T <sub>P</sub> =10ms		60	A <sup>2</sup> s
di/dt	通态电流上升值 Critical rate of rise of on-state current	F=120Hz, Tj=125°C		50	A/μs
I <sub>GM</sub>	门极峰值电流 Peak gate current	TP=20μs, Tj=125°C		4	A
P <sub>G(AV)</sub>	平均门极耗散功率 Average gate power dissipation	Tj=125°C		1	W
T <sub>stg</sub>	贮存结温范围 Storage junction temperature range			-40~+150	°C
T <sub>j</sub>	工作结温范围 Operating junction temperature range			-40~+125	°C

**电参数(除非另有规定, Tj=25°C) ELECTRICAL CHARACTERISTICS**

(Tj=25°C,unless otherwise specified)

参数 Parameter	符号 Symbol	规范值 Value			单位 Unit	测试条件 Test Conditions
		Min	Typ	Max		
触发电流 Gate trigger current	I <sub>GT</sub>	-	-	15	mA	V <sub>D</sub> =12V, I <sub>T</sub> =0.1A
触发电压 Gate trigger voltage	V <sub>GT</sub>	-	-	1.5	V	V <sub>D</sub> =12V, I <sub>T</sub> =0.1A
维持电流 Holding current	I <sub>H</sub>	-	-	50	mA	V <sub>D</sub> =12V, I <sub>T</sub> =0.1A
电压上升率 Rise of off-state voltage	dv/dt	50	-	-	V/μs	V <sub>D</sub> =67% V <sub>DRM</sub>
通态压降 Peak on-state voltage	V <sub>TM</sub>	-	-	1.7	V	I <sub>T</sub> =24A
断态漏电流 Peak repetitive forward blocking current	I <sub>DRM</sub> I <sub>RRM</sub>	-	-	5	μA	V <sub>RRM</sub> =V <sub>DRM</sub> , T <sub>j</sub> = 25 °C
		-	-	2	mA	V <sub>RRM</sub> =V <sub>DRM</sub> , T <sub>j</sub> = 125 °C

**热特性 THERMAL RESISTANCES**

符号 Symbol	参数 Parameter	数值 Value	单位 Unit
R <sub>th(j-c)</sub>	Junction to case(AC)	3	°C/W
R <sub>th(j-a)</sub>	Junction to ambient	75	°C/W

## 特征曲线

## ELECTRICAL CHARACTERISTICS (CURVES)

图1 最大耗散功率与平均通态电流关系

Fig.1. Maximum Power Dissipation Versus Average On-state Current

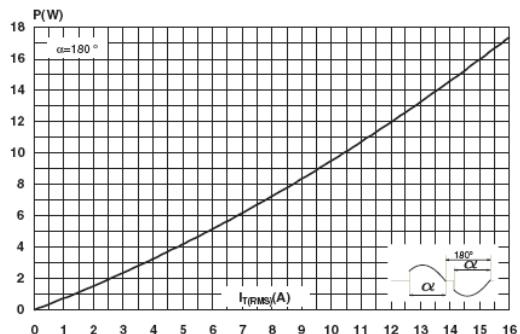


图3 通态特性

Fig.3. On-State Characteristics

图2 RMS通态电流与Tc温度关系

Fig.2. RMS On-state Current Versus TL

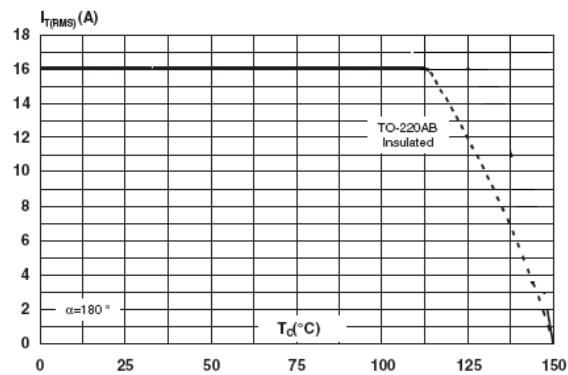


图4 通态浪涌峰值电流与周期数关系

Fig.4. Surge Peak On-state Current Versus Number Cycles

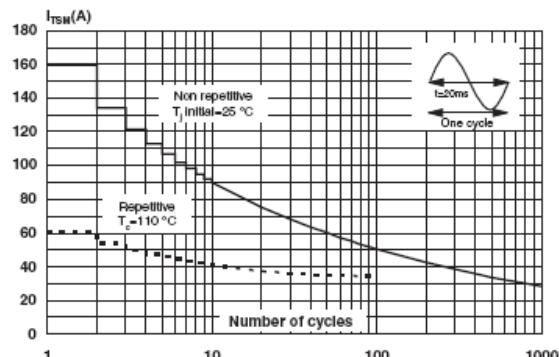
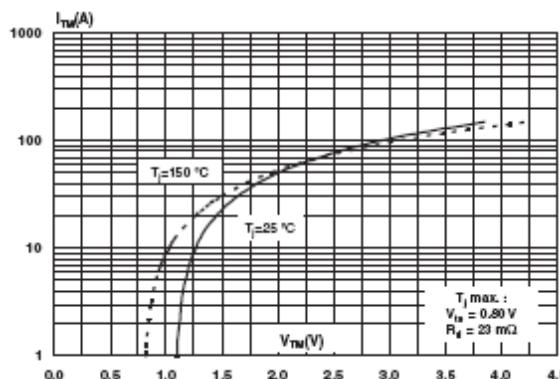
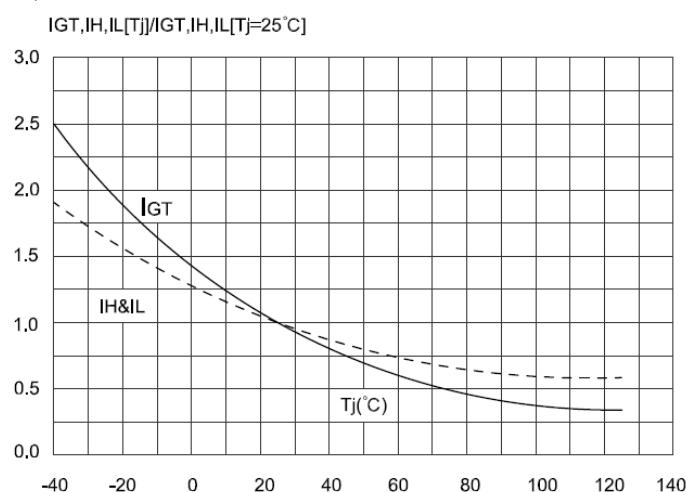


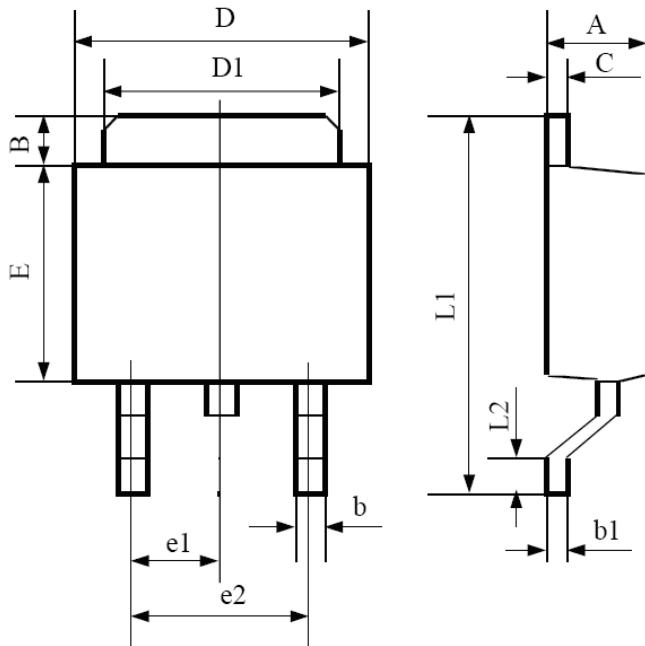
图5 IGT、IH、IL相对值（相对于25℃）与结温关系

Fig.5. Relative Variation Of Gate Trigger Current, Holding Current And Latching Current Versus Junction Temperature (Typical Value)



## 封装尺寸 PACKAGE MECHANICAL DATA

## TO-252



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	2.20	2.40	0.087	0.094
B	1.35	1.65	0.053	0.065
b	0.50	0.70	0.02	0.028
b1	0.45	0.56	0.017	0.022
C	0.46	0.56	0.018	0.022
D	6.35	6.65	0.25	0.262
D1	5.20	5.40	0.205	0.212
E	5.80	6.10	0.228	0.240
e1	2.25	2.35	0.089	0.093
e2	4.50	4.70	0.177	0.185
L1	9.80	10.40	0.386	0.409
L2	0.95	1.45	0.037	0.057

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